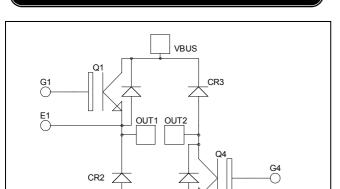
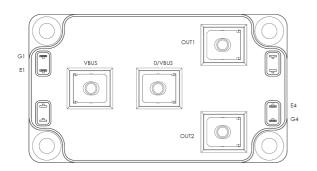


Asymmetrical - Bridge Trench + Field Stop IGBT3 Power Module



0/VBUS



$V_{CES} = 600V$ $I_C = 200A$ @ Tc = 80°C

Application

- Welding converters
- Switched Mode Power Supplies
- Switched Reluctance Motor Drives

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- · RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	290	
	Continuous Conector Current	$T_C = 80$ °C	200	A
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	400	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	625	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	400A @ 550V	

E4

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_{C} = 200A$	$T_j = 25$ °C		1.5	1.9	V
			$T_j = 150$ °C		1.7		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 2 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Min	Тур	Max	Unit	
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			12.3		nF
C_{oes}	Output Capacitance				0.8		
C_{res}	Reverse Transfer Capacitance				0.4		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ing (25°C)		115		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			45		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 200A$			225		ns
$T_{\rm f}$	Fall Time	$R_G = 2\Omega$		55			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_{C} = 200A$ $R_{G} = 2\Omega$			130		ns
T_{r}	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time				300		
$T_{\rm f}$	Fall Time				70		
Б	Т	$V_{GE} = \pm 15V$	$T_j = 25^{\circ}C$		1		m I
E _{on} Turn on Energ	Turn on Energy	$V_{\text{Bus}} = 300\text{V}$	$T_{j} = 150^{\circ}C$		1.8		mJ
E _{off}	Turn off Energy	$ \begin{aligned} & I_C = 200 A \\ & R_G = 2 \Omega \end{aligned} & \begin{aligned} & T_j = 25 ^{\circ} C \\ & T_j = 150 ^{\circ} C \end{aligned} $	$T_j = 25$ °C		5.7		mJ
				7		1111	

Diode ratings and characteristics

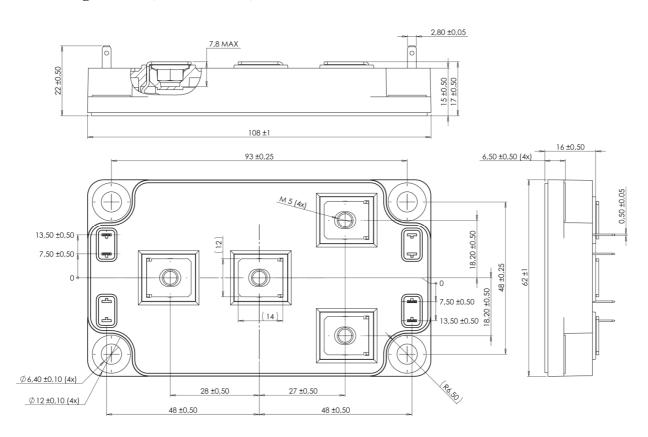
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	$V_R=600V$	$T_i = 25$ °C $T_i = 150$ °C			250 500	μΑ
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		200		A
V_{F}	Diode Forward Voltage	$I_F = 200A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.6	2	V
v _F			$T_{i} = 150^{\circ}C$		1.5		V
t _{rr}	Reverse Recovery Time	$I_F = 200A$ $V_R = 300V$ $di/dt = 2200A/\mu s$	$T_j = 25^{\circ}C$		130		- ns
			$T_{\rm j} = 150^{\circ}{\rm C}$		225		
Q _{rr}	Reverse Recovery Charge		$T_j = 25^{\circ}C$		9		ıı.C
			$T_{\rm j} = 150^{\circ}{\rm C}$		19		μС
Er	Reverse Recovery Energy	T	$T_j = 25$ °C		2.3		mJ
			$T_{i} = 150^{\circ}C$		4.7		111J



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	L Junction to Case Thermal Resistance		IGBT			0.24	°C/W
TthJC			Diode			0.4	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		175	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	
Wt	Package Weight					300	g

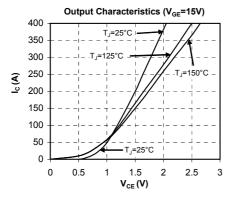
SP6 Package outline (dimensions in mm)

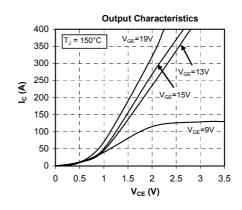


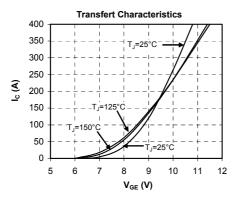
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

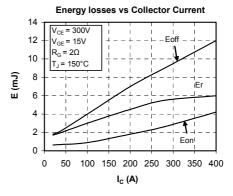


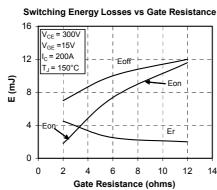
Typical Performance Curve

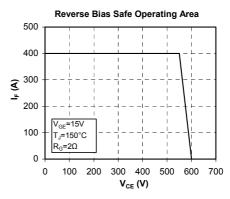


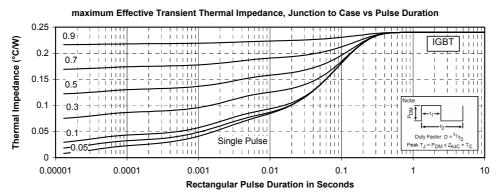




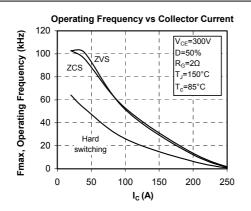


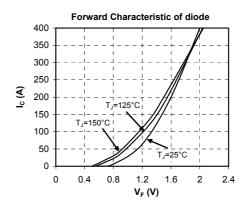


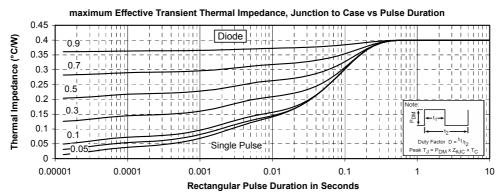












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